TÜV MANAGEMENT SERVICE

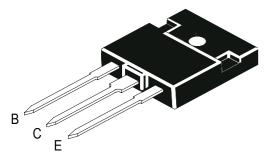


An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

PNP POWER TRANSISTOR

CSB 817F

TO 3P Plastic Package



Complementary CSD1047F

Audio Power Amplifier and DC to DC Converter

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	MIN	TYP	MAX	UNIT
Collector -Base Voltage(open emitter)	V_{CBO}	160			V
Collector -Emitter Voltage(open base)	V_{CEO}	140			V
Emitter Base Voltage(open collector)	V_{EBO}	6.0			V
Collector Current(DC)	I _C			12	Α
Collector Current (Pulse)	I _C			15	Α
Total Power Dissipation upto Tc=25° C	P_{tot}			90	W
Junction Temperature	T_j			150	°C
Storage Temperature	T_{stg}	-5	55 to +150		°C

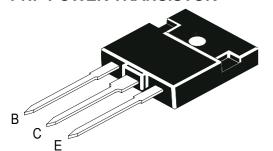
ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Cut off Current	I _{CBO}	V_{CB} =80V, I_{E} =0			0.1	mA
Emitter Cut off Current	I_{EBO}	V_{EB} =4 V , I_{C} =0			0.1	mA
Breakdown Voltages	$V_{\sf CEO}$	I_C =10mA, I_B =0	140			V
	V_{CBO}	I_C =5mA, I_E =0	160			V
	V_{EBO}	I_E =5mA, I_C =0	6.0			V
Saturation Voltage						
	$V_{CE(sat)}$	I_{C} =5A, I_{B} =0.5A			2.5	V
Base Emitter on Voltage	$V_{BE(on)}$	$I_C=1A$, $V_{CE}=5V$			1.5	V
DC Current Gain	h _{FE} *	$I_C=1A, V_{CE}=5V^{**}$	60		200	
		I_C =6A, V_{CE} =5V	20			
Output Capacitance at f =1MHz	C _o	V _{CB} =10V, I _E =0	300		pF	
Transition Frequency	f_T	$I_C=1A, V_{CE}=5V$		15		MHz

PNP POWER TRANSISTOR

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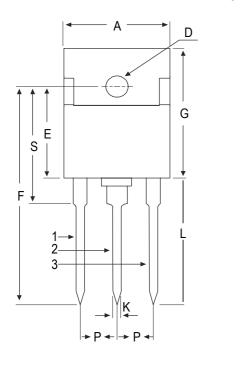


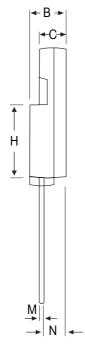


DESCRIPTION	SCRIPTION SYMBOL TEST CONDITION		MIN TYP		UNIT
SWITCHING TIME					
	V_{CC} =20V, I_{C} =1A=1	0			
	I _{B1} = -10 I _{B2} , RL =2	0 Ω			
Turn on time	t_on		0.25		μs
Storage time	t_s		1.61		μs
Fall time	t_{f}		0.53		μs

TO 3P Plastic Package

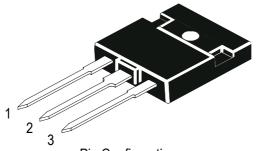
TO-3P (TO-218) Plastic Package





DIM	MIN	MAX
Α	15.80	16.40
В	5.20	5.70
С	3.80	4.20
D	Ø 3.30	Ø 3.60
E	14.50	15.10
F	33.25	36.75
G	20.75	21.25
Н	11.50	12.25
K	1.00	1.30
L	18.75	21.65
М	0.40	0.60
N	3.15	3.45
Р	5.21	5.72
S	18.75	19.25

All diminsions in mm.



- Pin Configuration
- 1. Base
- 2. Collector
- 3. Emitter

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-3P	100 pcs/polybag	628 gm/100 pcs	3" x 7.5" x 7.5"	0.3K	17" x 15" x 13.5"	4.8K	42 kgs

Notes CSB 817F

TO 3P Plastic Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the CDIL Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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CDIL is a registered Trademark of
Continental Device India Limited
C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com

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